
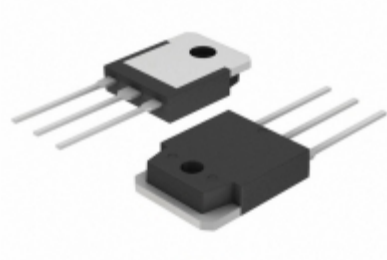
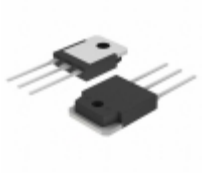
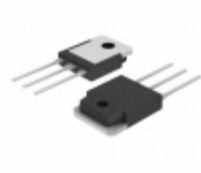
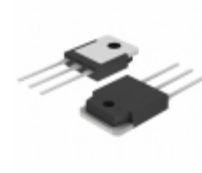
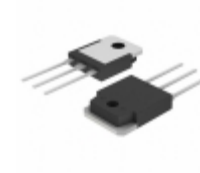
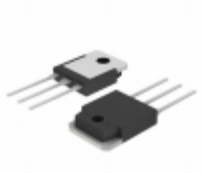
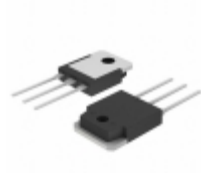
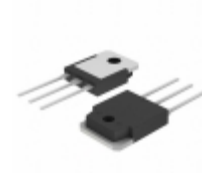
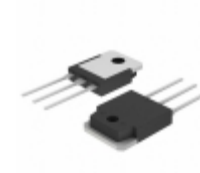
	<p><b>FQA28N50</b></p>
	<p><b>Hersteller-Teilenummer:</b> FQA28N50</p> <p><b>Hersteller / Marke:</b> Fairchild/ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 500V 28.4A TO-3P</p> <p><b>Datenblätter:</b>  <a href="#">FQA28N50.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 15906 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	FQA28N50
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 500V 28.4A TO-3P
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	15906 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-3P-3, SC-65-3
Supplier Device-Gehäuse	TO-3PN
Verlustleistung (max)	310W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	28.4A (Tc)
Rds On (Max) @ Id, Vgs	160 mOhm @ 14.2A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	140nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	5600pF @ 25V
Verpackung	Tube



















































FQA28N50 ist neu im Original, Suche FQA28N50 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQA28N50 Fairchild/ON Semiconductor mit Garantie und Vertrauen.  
Anfrage FQA28N50: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <b>FQA28N15_F109</b> Fairchild/ON Semiconductor MOSFET N-CH 150V 33A TO-3P	 <b>FQA28N15</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 150V 33A TO-3P	 <b>FQA28N50</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 28.4A TO-3P	 <b>FQA28N50F</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 28.4A TO-3P
 <b>FQA28N50_F109</b> Fairchild/ON Semiconductor MOSFET N-CH 500V 28.4A TO-3PN	 <b>FQA28N50_F109</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 28.4A TO-3PN	 <b>FQA28N15_F109</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 150V 33A TO-3P	 <b>FQA28N15</b> Fairchild/ON Semiconductor MOSFET N-CH 150V 33A TO-3P

### heiße Teile

Mehr

 FQA18N50	 FQA19N20C	 FQA19N20C	 FQA19N20L	 FQA19N20L
 FQA19N60	 FQA19N60	 FQA20N40	 FQA20N40	 FQA20N50
 FQA20N60	 FQA20N80	 FQA24N50	 FQA24N50	 FQA24N50F
 FQA24N50F	 FQA24N60	 FQA24N60	 FQA27N25	 FQA27N25
 FQA28N15	 FQA28N15	 FQA28N15_F109	 FQA28N15_F109	 FQA28N50
 FQA28N50F	 FQA28N50F	 FQA30N40	 FQA30N40	 FQA32N20C
 FQA32N20C	 FQA33N10	 FQA33N10	 FQA33N10L	 FQA33N10L
 FQA34N20	 FQA34N20	 FQA34N20L	 FQA34N20L	 FQA34N25
 FQA34N25	 FQA35N40	 FQA35N40	 FQA36P15	 FQA36P15
 FQA36P15_F109	 FQA36P15_F109	 FQA38N30	 FQA38N30	 FQA40N25

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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